

LMV431, LMV431A, LMV431B

www.ti.com

SNVS041F-MAY 2004-REVISED MAY 2005

LMV431/LMV431A/LMV431B Low-Voltage (1.24V) Adjustable Precision Shunt Regulators

Check for Samples: LMV431, LMV431A, LMV431B

FEATURES

- Low Voltage Operation/Wide Adjust Range (1.24V/30V)
- 0.5% Initial Tolerance (LMV431B)
- Temperature Compensated for Industrial Temperature Range (39 PPM/°C for the LMV431AI)
- Low Operation Current (55µA)
- Low Output Impedance (0.25Ω)
- Fast Turn-On Response

Low Cost

APPLICATIONS

- Shunt Regulator
- Series Regulator
- Current Source or Sink
- Voltage Monitor
- Error Amplifier
- 3V Off-Line Switching Regulator
- Low Dropout N-Channel Series Regulator

DESCRIPTION

The LMV431, LMV431A and LMV431B are precision 1.24V shunt regulators capable of adjustment to 30V. Negative feedback from the cathode to the adjust pin controls the cathode voltage, much like a non-inverting op amp configuration (Refer to Symbol and Functional diagrams). A two resistor voltage divider terminated at the adjust pin controls the gain of a 1.24V band-gap reference. Shorting the cathode to the adjust pin (voltage follower) provides a cathode voltage of a 1.24V.

The LMV431, LMV431A and LMV431B have respective initial tolerances of 1.5%, 1% and 0.5%, and functionally lends themselves to several applications that require zener diode type performance at low voltages. Applications include a 3V to 2.7V low drop-out regulator, an error amplifier in a 3V off-line switching regulator and even as a voltage detector. These parts are typically stable with capacitive loads greater than 10nF and less than 50pF.

The LMV431, LMV431A and LMV431B provide performance at a competitive price.

Connection Diagram

TO92: Plastic Package

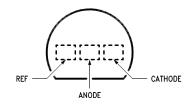
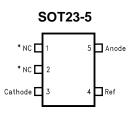


Figure 1. Top View



*Pin 1 is not internally connected.

*Pin 2 is internally connected to Anode pin. Pin 2 should be either floating or connected to Anode pin.

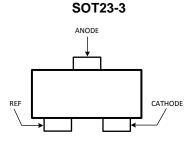
Figure 2. Top View

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.

LMV431, LMV431A, LMV431B

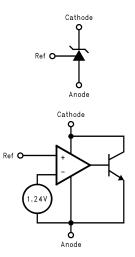
SNVS041F-MAY 2004-REVISED MAY 2005

www.ti.com

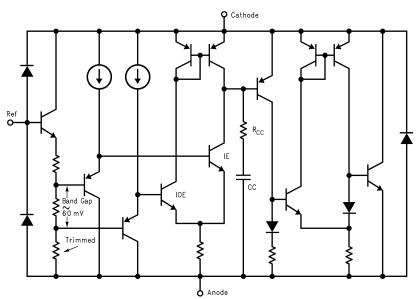




Symbol and Functional Diagrams



Simplified Schematic





www.ti.com

DC/AC Test Circuits for Table and Curves

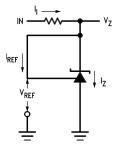
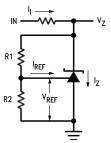


Figure 4. Test Circuit for $V_Z = V_{REF}$



Note: $V_Z = V_{REF} (1 + R1/R2) + I_{REF} R1$

Figure 5. Test Circuit for $V_Z > V_{REF}$

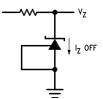


Figure 6. Test Circuit for Off-State Current

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

LMV431, LMV431A, LMV431B



www.ti.com

Absolute Maximum Ratings ⁽¹⁾

Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	
Industrial (LMV431AI, LMV431I)	−40°C to +85°C
Commercial (LMV431AC, LMV431C, LMV431BC)	0°C to +70°C
Lead Temperature	
TO92 Package/SOT23 -5,-3 Package	
(Soldering, 10 sec.)	265°C
Internal Power Dissipation ⁽²⁾ TO92	0.78W
SOT23-5, -3 Package	0.28W
Cathode Voltage	35V
Continuous Cathode Current	-30 mA to +30mA
Reference Input Current range	05mA to 3mA

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its rated operating conditions.

(2) Ratings apply to ambient temperature at 25°C. Above this temperature, derate the TO92 at 6.2 mW/°C, and the SOT23-5 at 2.2 mW/°C. See derating curve in Operating Condition section..

Operating Conditions

Cathode Voltage	V _{REF} to 30V
Cathode Current	0.1 mA to 15mA
Temperature range	
LMV431AI	$-40^{\circ}C \le T_A \le 85^{\circ}C$
Thermal Resistance $(\theta_{JA})^{(1)}$	
SOT23-5, -3 Package	455 °C/W
TO-92 Package	161 °C/W
Derating Curve (Slope = $-1/\theta_{JA}$)	

(1) $T_{J Max} = 150^{\circ}C$, $T_{J} = T_{A}$ + ($\theta_{JA} P_{D}$), where P_{D} is the operating power of the device.

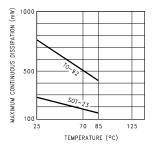


Figure 7. P_D (max) vs Temperature



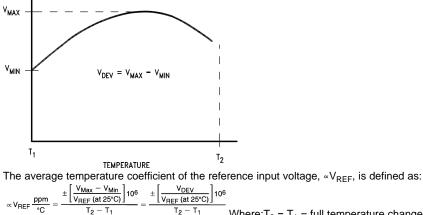
www.ti.com

LMV431C Electrical Characteristics

25°C unless otherwise specified

Symbol	Parameter	Conditio	ons	Min	Тур	Мах	Unit s
V _{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10mA$	$T_A = 25^{\circ}C$	1.222	1.24	1.258	
		(See Figure 4)	T _A = Full Range	1.21		1.27	V
V_{DEV}	Deviation of Reference Input Voltage Over Temperature ⁽¹⁾	$V_Z = V_{REF}$, $I_Z = 10mA$, $T_A = Full Range (See Figure$	re 4)		4	12	mV
$\Delta V_{REF}/\Delta V_Z$	Ratio of the Change in Reference Voltage to the Change in Cathode Voltage	$ I_Z = 10mA (see Figure 5) V_Z from V_{REF} to 6V R_1 = 10k, R_2 = \infty and 2.6k $			-1.5	-2.7	mV/ V
I _{REF}	Reference Input Current	$\begin{array}{l} R_1 = 10 k\Omega, R_2 = \infty \\ I_{I} = 10 mA \; (see \; \textit{Figure 5}) \end{array}$			0.15	0.5	μA
∝I _{REF}	Deviation of Reference Input Current over Temperature	$ \begin{array}{l} R_1 = 10 k \Omega, R_2 = \infty, \\ I_{I} = 10 m A, T_{A} = Full \; Range \end{array} $	(see Figure 5)		0.05	0.3	μA
I _{Z(MIN)}	Minimum Cathode Current for Regulation	V _Z = V _{REF} (see Figure 4)			55	80	μA
I _{Z(OFF)}	Off-State Current	V _Z =6V, V _{REF} = 0V (see Figu	ure 6)		0.001	0.1	μA
r _Z	Dynamic Output Impedance ⁽²⁾	$V_Z = V_{REF}$, $I_Z = 0.1$ mA to 15 Frequency = 0Hz (see Figu			0.25	0.4	Ω

Deviation of reference input voltage, V_{DEV}, is defined as the maximum variation of the reference input voltage over the full temperature (1) range.See following:



Where: $T_2 - T_1$ = full temperature change. $\sim V_{REF}$ can be positive or negative depending

RUMENTS

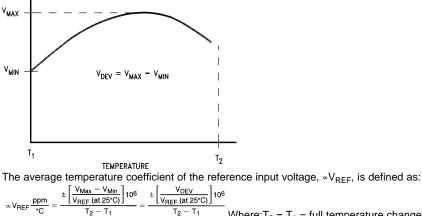
www.ti.com

LMV4311 Electrical Characteristics

 $T_{4} = 25^{\circ}C$ unless otherwise specified

Symbol	Parameter	Conditio	ns	Min	Тур	Max	Unit s
V _{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10mA$	$T_A = 25^{\circ}C$	1.222	1.24	1.258	v
		(See Figure 4)	T _A = Full Range	1.202		1.278	v
V_{DEV}	Deviation of Reference Input Voltage Over Temperature ⁽¹⁾	$V_Z = V_{REF}, I_Z = 10mA,$ $T_A = Full Range (See Figure$	e 4)		6	20	mV
$\Delta V_{REF}/\Delta V_Z$	Ratio of the Change in Reference Voltage to the Change in Cathode Voltage	$\begin{array}{l} I_Z = 10 \text{mA} \ (\text{see Figure 5} \) \\ V_Z \ \text{from} \ V_{\text{REF}} \ \text{to} \ 6 V \\ R_1 = 10 \text{k}, \ R_2 = \infty \ \text{and} \ 2.6 \text{k} \end{array}$			-1.5	-2.7	mV/ V
I _{REF}	Reference Input Current	$R_1 = 10kΩ$, $R_2 = ∞$ $I_1 = 10mA$ (see Figure 5)			0.15	0.5	μA
∝I _{REF}	Deviation of Reference Input Current over Temperature	$R_1 = 10kΩ$, $R_2 = ∞$, $I_1 = 10mA$, $T_A = Full Range$	(see Figure 5)		0.1	0.4	μA
I _{Z(MIN)}	Minimum Cathode Current for Regulation	V _Z = V _{REF} (see Figure 4)			55	80	μA
I _{Z(OFF)}	Off-State Current	$V_Z = 6V, V_{REF} = 0V$ (see Fig	jure 6)		0.001	0.1	μA
r _Z	Dynamic Output Impedance ⁽²⁾	$V_Z = V_{REF}$, $I_Z = 0.1$ mA to 15 Frequency = 0Hz (see Figur			0.25	0.4	Ω

(1) Deviation of reference input voltage, V_{DEV}, is defined as the maximum variation of the reference input voltage over the full temperature range.See following:



Where: $T_2 - T_1$ = full temperature change. $\sim V_{REF}$ can be positive or negative depending

on whether the slope is positive or negative. Example: $V_{DEV} = 6.0 \text{mV}$, $_{REF} = 1240 \text{mV}$, $T_2 - T_1 = 125^{\circ}\text{C}$. (2) The dynamic output impedance, r_Z , is defined as: $r_Z = \frac{\Delta V_Z}{\Delta I_Z}$ When the device is programmed with two external resistors, R1 and R2, (see *Figure 5*), the dynamic output impedance of the overall circuit, r_Z , is defined as: $r_Z = \frac{\Delta V_Z}{\Delta I_Z} \simeq \left[r_Z \left(1 + \frac{R1}{R2} \right) \right]$

6



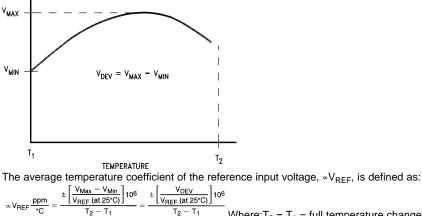
www.ti.com

LMV431AC Electrical Characteristics

25°C upleas athemulas aposified

Symbol	Parameter	Condit	Min	Тур	Max	Unit s	
V _{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10 \text{ mA}$	$T_A = 25^{\circ}C$	1.228	1.24	1.252	v
		(See Figure 4)	T _A = Full Range	1.221		1.259	v
V_{DEV}	Deviation of Reference Input Voltage Over Temperature ⁽¹⁾	$V_Z = V_{REF}, I_Z = 10mA,$ $T_A = Full Range (See Figu$	ure 4)		4	12	mV
$\Delta V_{REF}/\Delta V_Z$	Ratio of the Change in Reference Voltage to the Change in Cathode Voltage	$I_Z = 10 \text{ mA} \text{ (see Figure 5)}$ $V_Z \text{ from } V_{REF} \text{ to } 6V$ $R_1 = 10k, R_2 = \infty \text{ and } 2.6k$			-1.5	-2.7	mV/ V
I _{REF}	Reference Input Current	$\begin{array}{l} R_1 = 1 \ k\Omega, \ R_2 = \infty \\ I_1 = 10 \ mA \ (see \ \textit{Figure 5}) \end{array}$			0.15	0.50	μA
∝I _{REF}	Deviation of Reference Input Current over Temperature	$R_1 = 10$ kΩ, $R_2 = ∞$, $I_1 = 10$ mA, $T_A =$ Full Rang	ge (see Figure 5)		0.05	0.3	μA
I _{Z(MIN)}	Minimum Cathode Current for Regulation	V _Z = V _{REF} (see Figure 4)			55	80	μA
I _{Z(OFF)}	Off-State Current	$V_Z = 6V, V_{REF} = 0V$ (see F	Figure 6)		0.001	0.1	μA
r _Z	Dynamic Output Impedance (2)	$V_Z = V_{REF}$, $I_Z = 0.1$ mA to 1 Frequency = 0 Hz (see Fig.			0.25	0.4	Ω

Deviation of reference input voltage, V_{DEV}, is defined as the maximum variation of the reference input voltage over the full temperature (1) range.See following:



Where: $T_2 - T_1$ = full temperature change. $\sim V_{REF}$ can be positive or negative depending



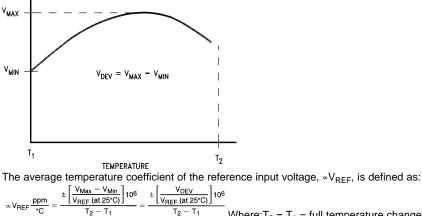
www.ti.com

LMV431AI Electrical Characteristics

 $T_{4} = 25^{\circ}C$ unless otherwise specified

Symbol	Parameter	Conditio	ns	Min	Тур	Max	Unit s
V _{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10mA$	T _A = 25°C	1.228	1.24	1.252	
		(See Figure 4)	T _A = Full Range	1.215		1.265	V
V_{DEV}	Deviation of Reference Input Voltage Over Temperature ⁽¹⁾	$V_Z = V_{REF}$, $I_Z = 10mA$, $T_A = Full Range (See Figure)$	e 4)		6	20	mV
$\Delta V_{REF}/\Delta V_Z$	Ratio of the Change in Reference Voltage to the Change in Cathode Voltage	$\begin{array}{l} I_Z = 10 \text{mA} \; (\text{see Figure 5} \;) \\ V_Z \; \text{from } V_{\text{REF}} \; \text{to} \; 6V \\ R_1 = 10 \text{k}, \; R_2 = \infty \; \text{and} \; 2.6 \text{k} \end{array}$			-1.5	-2.7	mV/ V
I _{REF}	Reference Input Current	$\begin{array}{l} R_1 = 10 k \Omega, R_2 = \infty \\ I_1 = 10 mA \; (see \; \textit{Figure 5}) \end{array}$			0.15	0.5	μA
∝I _{REF}	Deviation of Reference Input Current over Temperature	$R_1 = 10k\Omega, R_2 = \infty,$ $I_1 = 10mA, T_A = Full Range$	(see Figure 5)		0.1	0.4	μA
I _{Z(MIN)}	Minimum Cathode Current for Regulation	V _Z = V _{REF} (see Figure 4)			55	80	μA
I _{Z(OFF)}	Off-State Current	$V_Z = 6V, V_{REF} = 0V$ (see Fig.	gure 6)		0.001	0.1	μA
r _Z	Dynamic Output Impedance ⁽²⁾	$V_Z = V_{REF}$, $I_Z = 0.1$ mA to 15 Frequency = 0Hz (see Figure			0.25	0.4	Ω

(1) Deviation of reference input voltage, V_{DEV}, is defined as the maximum variation of the reference input voltage over the full temperature range.See following:



Where: $T_2 - T_1$ = full temperature change. $\sim V_{REF}$ can be positive or negative depending



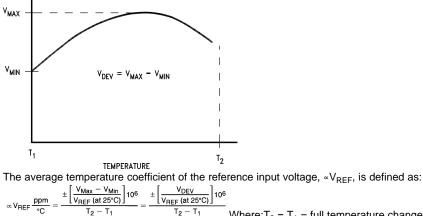
www.ti.com

LMV431BC Electrical Characteristics

25°C upleas athemulas aposified

Symbol	Parameter	Conditio	Min	Тур	Max	Unit s	
V _{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10mA$	$T_A = 25^{\circ}C$	1.234	1.24	1.246	
		(See Figure 4)	T _A = Full Range	1.227		1.253	V
V_{DEV}	Deviation of Reference Input Voltage Over Temperature ⁽¹⁾	$V_Z = V_{REF}$, $I_Z = 10mA$, $T_A = Full Range (See Figure)$	re 4)		4	12	mV
$\Delta V_{REF}/\Delta V_Z$	Ratio of the Change in Reference Voltage to the Change in Cathode Voltage	$ \begin{array}{l} I_Z = 10 \text{mA} \; (\text{see Figure 5} \;) \\ V_Z \; \text{from} \; V_{\text{REF}} \; \text{to} \; 6V \\ R_1 = 10 \text{k}, \; R_2 = \infty \; \text{and} \; 2.6 \text{k} \end{array} $			-1.5	-2.7	mV/ V
I _{REF}	Reference Input Current	$R_1 = 10kΩ$, $R_2 = ∞$ $I_1 = 10mA$ (see Figure 5)			0.15	0.50	μA
∝I _{REF}	Deviation of Reference Input Current over Temperature	$R_1 = 10k\Omega$, $R_2 = ∞$, $I_1 = 10mA$, $T_A = Full Range$	(see Figure 5)		0.05	0.3	μA
I _{Z(MIN)}	Minimum Cathode Current for Regulation	V _Z = V _{REF} (see Figure 4)			55	80	μA
I _{Z(OFF)}	Off-State Current	$V_Z = 6V, V_{REF} = 0V$ (see F	igure 6)		0.001	0.1	μA
r _Z	Dynamic Output Impedance ⁽²⁾	$V_Z = V_{REF}$, $I_Z = 0.1 mA$ to 15 Frequency = 0Hz (see Figu			0.25	0.4	Ω

Deviation of reference input voltage, V_{DEV}, is defined as the maximum variation of the reference input voltage over the full temperature (1) range.See following:



Where: $T_2 - T_1$ = full temperature change. $\sim V_{REF}$ can be positive or negative depending



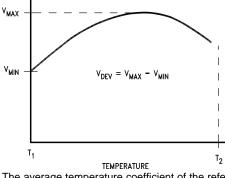
www.ti.com

LMV431BI Electrical Characteristics

 $T_A = 25^{\circ}C$ unless otherwise specified

Symbol	Parameter	Conditio	ns	Min	Тур	Мах	Unit s
V _{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10mA$	$T_A = 25^{\circ}C$	1.234	1.24	1.246	
		(See Figure 4)	T _A = Full Range	1.224		1.259	V
V_{DEV}	Deviation of Reference Input Voltage Over Temperature ⁽¹⁾	$V_Z = V_{REF}$, $I_Z = 10mA$, $T_A = Full Range (See Figure$	e 4)		6	20	mV
$\Delta V_{REF}/\Delta V_Z$	Ratio of the Change in Reference Voltage to the Change in Cathode Voltage	$I_Z = 10mA (see Figure 5)$ V_Z from V_{REF} to 6V $R_1 = 10k, R_2 = \infty$ and 2.6k			-1.5	-2.7	mV/ V
I _{REF}	Reference Input Current	$\begin{array}{l} R_1 = 10 k\Omega, R_2 = \infty \\ I_1 = 10 mA \; (see \; \textit{Figure 5}) \end{array}$			0.15	0.50	μA
∝I _{REF}	Deviation of Reference Input Current over Temperature	$ \begin{array}{l} R_1 = 10 k \Omega, R_2 = \infty, \\ I_{I} = 10 m A, T_{A} = Full \; Range \end{array} $	(see Figure 5)		0.1	0.4	μA
I _{Z(MIN)}	Minimum Cathode Current for Regulation	V _Z = V _{REF} (see Figure 4)			55	80	μA
I _{Z(OFF)}	Off-State Current	$V_Z = 6V, V_{REF} = 0V$ (see Fig.	gure 6)		0.001	0.1	μA
r _Z	Dynamic Output Impedance ⁽²⁾	$V_Z = V_{REF}$, $I_Z = 0.1$ mA to 15 Frequency = 0Hz (see Figure			0.25	0.4	Ω

(1) Deviation of reference input voltage, V_{DEV}, is defined as the maximum variation of the reference input voltage over the full temperature range.See following:



The average temperature coefficient of the reference input voltage, ${}_{\sim}V_{REF}$, is defined as:

 $\propto V_{\mathsf{REF}} \frac{\mathsf{ppm}}{^\circ\mathsf{C}} = \frac{\pm \left[\frac{V_{\mathsf{Max}} - V_{\mathsf{Min}}}{V_{\mathsf{REF}} (at \, 25^\circ\mathsf{C})}\right] 10^6}{T_2 - T_1} = \frac{\pm \left[\frac{V_{\mathsf{DEV}}}{V_{\mathsf{REF}} (at \, 25^\circ\mathsf{C})}\right] 10^6}{T_2 - T_1}$

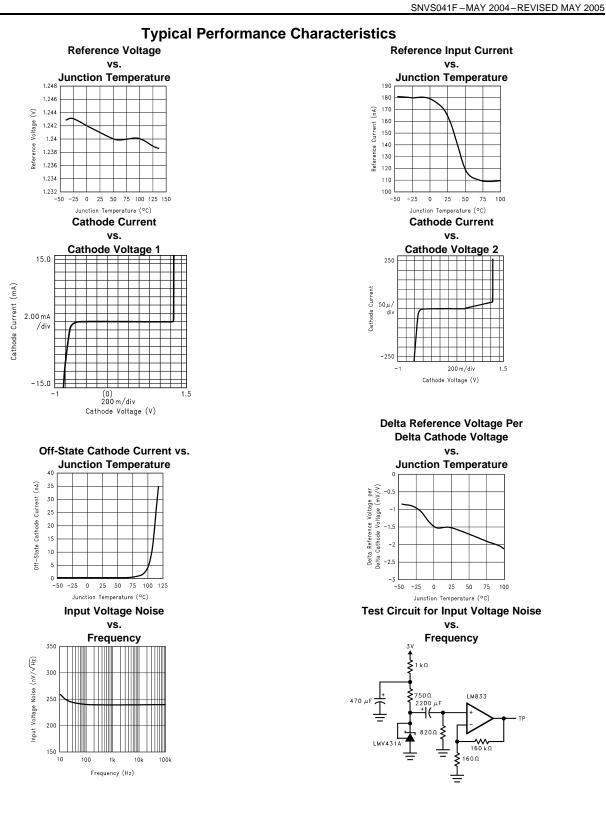
Where: $T_2 - T_1$ = full temperature change. $\sim V_{REF}$ can be positive or negative depending $\sim V_{REF} = \left[\frac{6.0 \text{ mV}}{1240 \text{ mV}}\right]_{106} = +39 \text{ nmm/}^2$

on whether the slope is positive or negative. Example: $V_{\text{DEV}} = 6.0 \text{mV}$, $_{\text{REF}} = 1240 \text{mV}$, $T_2 - T_1 = 125^{\circ}\text{C}$. $^{\text{cv}}V_{\text{REF}} = \frac{\lfloor 1240 \text{ mV} \rfloor^{10^{\circ}}}{125^{\circ}\text{C}} = +39 \text{ ppm/}^{\circ}\text{C}$ (2) The dynamic output impedance, r_Z , is defined as: $r_Z = \frac{\Delta V_Z}{\Delta I_Z}$ When the device is programmed with two external resistors, R1 and R2, (see *Figure 5*), the dynamic output impedance of the overall circuit, r_Z , is defined as: $r_Z = \frac{\Delta V_Z}{\Delta I_Z} \approx \left[r_Z \left(1 + \frac{R1}{R_2} \right) \right]$



EXAS

NSTRUMENTS



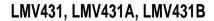
LMV431, LMV431A, LMV431B

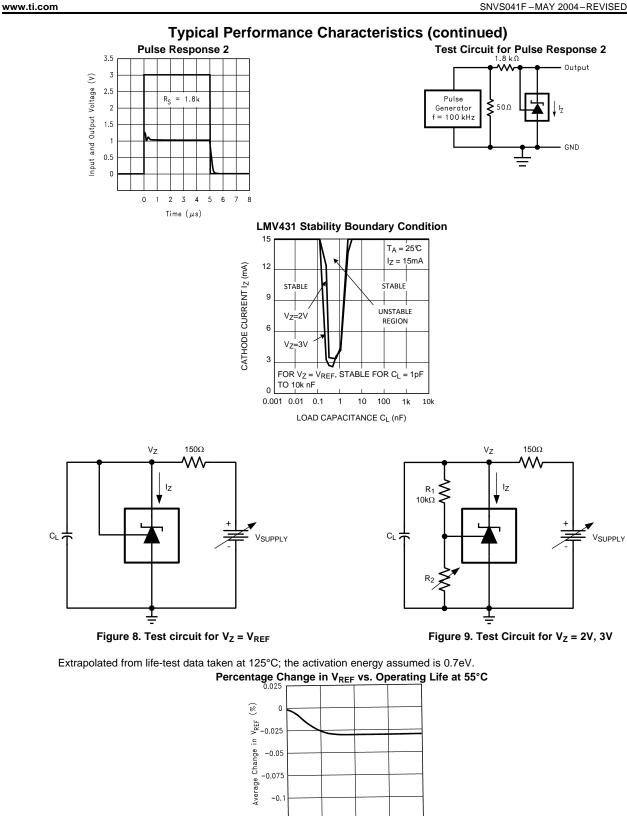


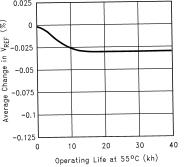
SNVS041F-MAY 2004-REVISED MAY 2005

www.ti.com **Typical Performance Characteristics (continued)** Low Frequency Peak to Peak Noise Test Circuit for Peak to Peak Noise (BW= 0.1Hz to 10Hz) Ĵ ≶ 1kΩ 2 μV/di 750Ω LM833 470 μF 2200 µF ≶ 820Ω 1 s/div LMV431A 0 160.0 Small Signal Voltage Gain and Phase Shift Test Circuit For Voltage Gain and Phase Shift vs. vs Frequency Frequency 80 Output 70 36 = 10 m 60 .8 kΩ 72 180Ω 50 108 Shift (°) 10 µF 40 144 Gain (dB) 30 180 Iŧ 5V 20 hase Ş 10 4.3 k.0 GND -10 -20 = 100 10k 100k 1 M 1k Frequency (Hz) **Reference Impedance Test Circuit for Reference Impedance** vs. vs. Frequency Frequency 100 Reference Impedance (Ω) 10 100 <u>Ω</u> = 10 mA I₇ 0. Ħ 0.01 1k 10k 100k 1 M 10M Frequency (Hz) **Pulse Response 1 Test Circuit for Pulse Response 1** 3.5 18 k.0 Output 3 Input and Output Voltage (V) Input 2.5 Pulse 2 ۶ 50Ω = 184 Re Generator f = 100 kHz 1.5 Output 1 GND 0.5 = 0 2 3 4 5 6 7 8 0 1 Time (μ s)

Copyright © 2004–2005, Texas Instruments Incorporated







EXAS

INSTRUMENTS

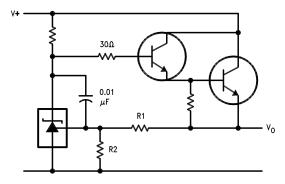


www.ti.com

SNVS041F-MAY 2004-REVISED MAY 2005

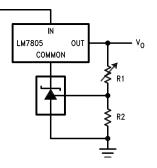
TYPICAL APPLICATIONS

Figure 10. Series Regulator



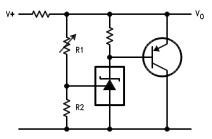
 $V_{O}\approx\left(1+\frac{R1}{R2}\right)V_{REF}$

Figure 11. Output Control of a Three Terminal Fixed Regulator



 $V_{O} = \left(1 + \frac{R1}{R2}\right) V_{REF}$ $V_{O MIN} = V_{REF} + 5V$

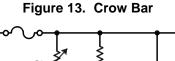




 $V_{O} \approx \left(1 + \frac{R1}{R2}\right) V_{REF}$

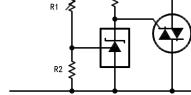


www.ti.com



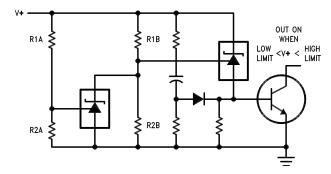
V+

۷٥



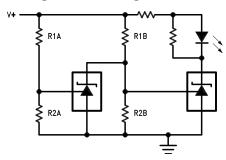
 $V_{\text{LIMIT}} \approx \left(1 + \frac{\text{R1}}{\text{R2}} \right) V_{\text{REF}}$

Figure 14. Over Voltage/Under VoltageProtection Circuit



$$\begin{split} \text{LOW LIMIT} &\approx V_{\text{REF}} \left(1 + \frac{\text{R1B}}{\text{R2B}}\right) + V_{\text{BE}} \\ \text{HIGH LIMIT} &\approx V_{\text{REF}} \left(1 + \frac{\text{R1A}}{\text{R2A}}\right) \end{split}$$

Figure 15. Voltage Monitor



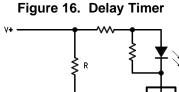
$$\begin{split} \text{LOW LIMIT} &\approx V_{\text{REF}} \left(1 + \frac{\text{R1B}}{\text{R2B}}\right) & \begin{array}{c} \text{LED ON WHEN} \\ \text{LOW LIMIT} &< V^+ &< \text{HIGH LIMIT} \\ \end{array} \\ \text{HIGH LIMIT} &\approx V_{\text{REF}} \left(1 + \frac{\text{R1A}}{\text{R2A}}\right) \end{split}$$

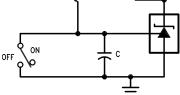
LMV431, LMV431A, LMV431B

Texas Instruments

SNVS041F-MAY 2004-REVISED MAY 2005

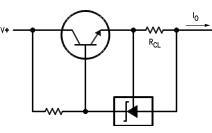
www.ti.com





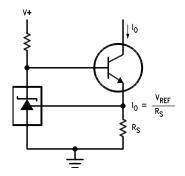
 $\mathsf{DELAY} = \mathsf{R} \bullet \mathsf{C} \bullet \ \ln \frac{\mathsf{V} +}{(\mathsf{V}^+) - \mathsf{V}_\mathsf{REF}}$





 $I_O = \frac{V_{REF}}{R_{CL}}$







9-Feb-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
LMV431ACM5	ACTIVE	SOT-23	DBV	5	1000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	N09A	Samples
LMV431ACM5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	N09A	Samples
LMV431ACM5X	ACTIVE	SOT-23	DBV	5	3000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	N09A	Samples
LMV431ACM5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	N09A	Samples
LMV431AIM5	ACTIVE	SOT-23	DBV	5	1000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	N08A	Samples
LMV431AIM5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	N08A	Samples
LMV431AIM5X	ACTIVE	SOT-23	DBV	5	3000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	N08A	Samples
LMV431AIM5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	N08A	Samples
LMV431AIMF	ACTIVE	SOT-23	DBZ	3	1000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	RLA	Samples
LMV431AIMF/NOPB	ACTIVE	SOT-23	DBZ	3	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	RLA	Samples
LMV431AIMFX	ACTIVE	SOT-23	DBZ	3	3000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	RLA	Samples
LMV431AIMFX/NOPB	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	RLA	Samples
LMV431AIZ/LFT3	ACTIVE	TO-92	LP	3	2000	Green (RoHS & no Sb/Br)	SNCU	Level-1-NA-UNLIM		LMV431 AIZ	Samples
LMV431AIZ/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SNCU	Level-1-NA-UNLIM	-40 to 85	LMV431 AIZ	Samples
LMV431BCM5	ACTIVE	SOT-23	DBV	5	1000	TBD	CU SNPB	Level-1-260C-UNLIM		N09C	Samples
LMV431BCM5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		N09C	Samples
LMV431BCM5X	ACTIVE	SOT-23	DBV	5	3000	TBD	CU SNPB	Level-1-260C-UNLIM		N09C	Samples
LMV431BCM5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		N09C	Samples



9-Feb-2013

Orderable Device	Status	Package Type	•	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing			(2)		(3)		(4)	
LMV431BIMF	ACTIVE	SOT-23	DBZ	3	1000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	RLB	Samples
LMV431BIMF/NOPB	ACTIVE	SOT-23	DBZ	3	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	RLB	Samples
LMV431BIMFX	ACTIVE	SOT-23	DBZ	3	3000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	RLB	Samples
LMV431BIMFX/NOPB	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	RLB	Samples
LMV431CM5	ACTIVE	SOT-23	DBV	5	1000	TBD	CU SNPB	Level-1-260C-UNLIM	0 to 70	N09B	Samples
LMV431CM5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	N09B	Samples
LMV431CM5X	ACTIVE	SOT-23	DBV	5	3000	TBD	CU SNPB	Level-1-260C-UNLIM	0 to 70	N09B	Samples
LMV431CM5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	N09B	Samples
LMV431CZ/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SNCU	Level-1-NA-UNLIM	0 to 70	LMV431 CZ	Samples
LMV431IM5	ACTIVE	SOT-23	DBV	5	1000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	N08B	Samples
LMV431IM5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	N08B	Samples
LMV431IM5X	ACTIVE	SOT-23	DBV	5	3000	TBD	CU SNPB	Level-1-260C-UNLIM	-40 to 85	N08B	Samples
LMV431IM5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	N08B	Samples
LMV431IZ/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SNCU	Level-1-NA-UNLIM	-40 to 85	LMV431 IZ	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.



www.ti.com

9-Feb-2013

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

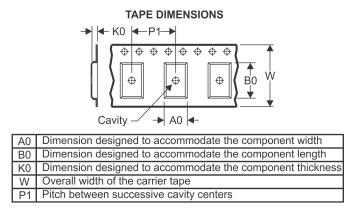
PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV431ACM5	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431ACM5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431ACM5X	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431ACM5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431AIM5	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431AIM5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431AIM5X	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431AIM5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431AIMF	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LMV431AIMF/NOPB	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LMV431AIMFX	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LMV431AIMFX/NOPB	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LMV431BCM5	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431BCM5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431BCM5X	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431BCM5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431BIMF	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LMV431BIMF/NOPB	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3

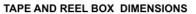
PACKAGE MATERIALS INFORMATION

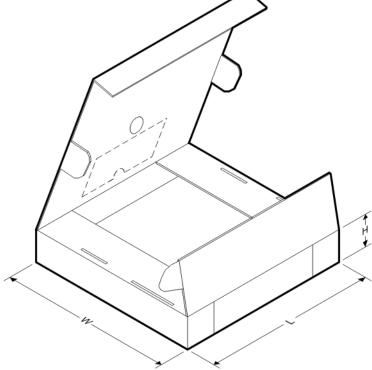


www.ti.com

17-Nov-2012

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV431BIMFX	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LMV431BIMFX/NOPB	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LMV431CM5	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431CM5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431CM5X	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431CM5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431IM5	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431IM5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431IM5X	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV431IM5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3





*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV431ACM5	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431ACM5/NOPB	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431ACM5X	SOT-23	DBV	5	3000	206.0	191.0	90.0
LMV431ACM5X/NOPB	SOT-23	DBV	5	3000	206.0	191.0	90.0
LMV431AIM5	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431AIM5/NOPB	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431AIM5X	SOT-23	DBV	5	3000	206.0	191.0	90.0

PACKAGE MATERIALS INFORMATION

TEXAS INSTRUMENTS

www.ti.com

17-Nov-2012

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV431AIM5X/NOPB	SOT-23	DBV	5	3000	206.0	191.0	90.0
LMV431AIMF	SOT-23	DBZ	3	1000	203.0	190.0	41.0
LMV431AIMF/NOPB	SOT-23	DBZ	3	1000	203.0	190.0	41.0
LMV431AIMFX	SOT-23	DBZ	3	3000	206.0	191.0	90.0
LMV431AIMFX/NOPB	SOT-23	DBZ	3	3000	206.0	191.0	90.0
LMV431BCM5	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431BCM5/NOPB	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431BCM5X	SOT-23	DBV	5	3000	206.0	191.0	90.0
LMV431BCM5X/NOPB	SOT-23	DBV	5	3000	206.0	191.0	90.0
LMV431BIMF	SOT-23	DBZ	3	1000	203.0	190.0	41.0
LMV431BIMF/NOPB	SOT-23	DBZ	3	1000	203.0	190.0	41.0
LMV431BIMFX	SOT-23	DBZ	3	3000	206.0	191.0	90.0
LMV431BIMFX/NOPB	SOT-23	DBZ	3	3000	206.0	191.0	90.0
LMV431CM5	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431CM5/NOPB	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431CM5X	SOT-23	DBV	5	3000	206.0	191.0	90.0
LMV431CM5X/NOPB	SOT-23	DBV	5	3000	206.0	191.0	90.0
LMV431IM5	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431IM5/NOPB	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMV431IM5X	SOT-23	DBV	5	3000	206.0	191.0	90.0
LMV431IM5X/NOPB	SOT-23	DBV	5	3000	206.0	191.0	90.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

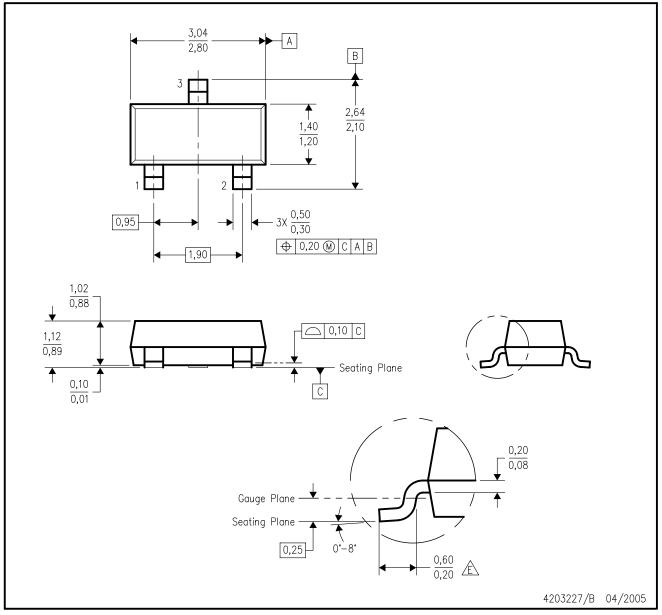
A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DBZ (R-PDSO-G3)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

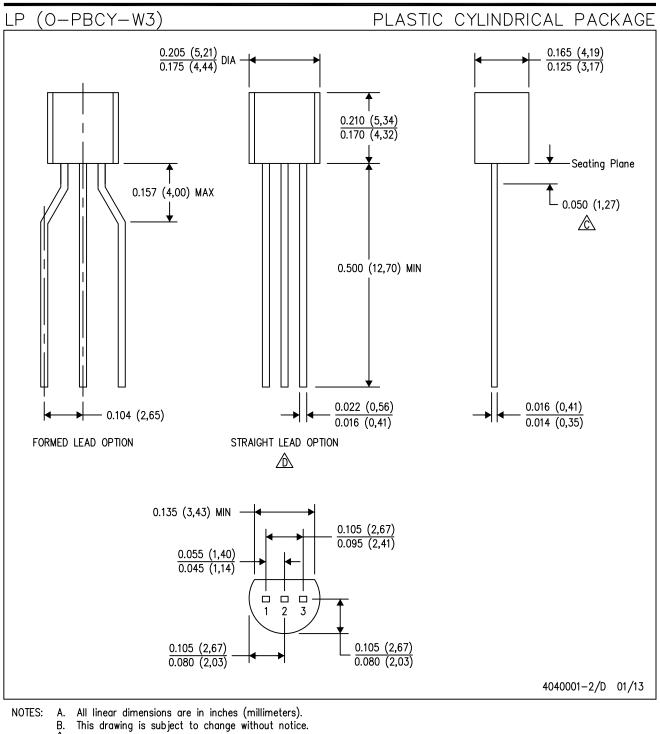
B. This drawing is subject to change without notice.

C. Lead dimensions are inclusive of plating.

D. Body dimensions are exclusive of mold flash and protrusion. Mold flash and protrusion not to exceed 0.25 per side.

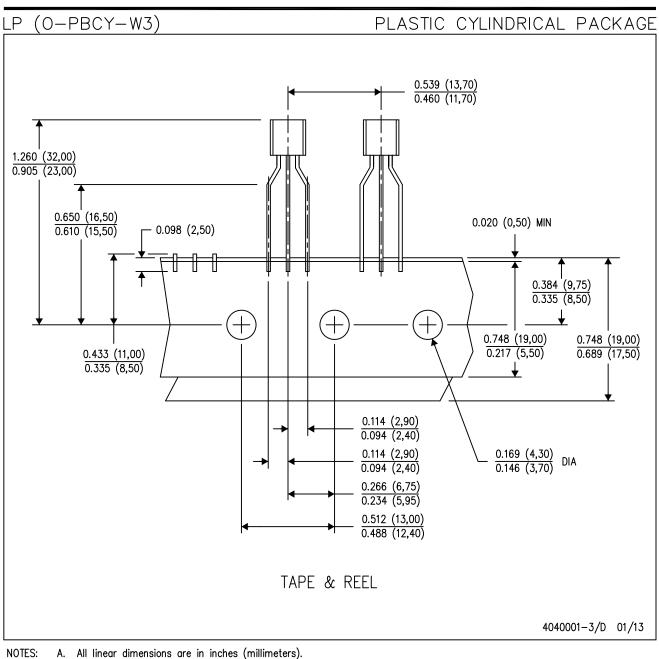
E Falls within JEDEC TO-236 variation AB, except minimum foot length.





- 🖄 Lead dimensions are not controlled within this area.
- Falls within JEDEC TO-226 Variation AA (TO-226 replaces TO-92).
- E. Shipping Method:
 - Straight lead option available in either bulk pack or tape & reel.
 - Formed lead option available in tape & reel or ammo pack.
 - Specific products can be offered in limited combinations of shipping mediums and lead options.
 - Consult product folder for more information on available options.





Α.

B. This drawing is subject to change without notice.

C. Tape and Reel information for the Formed Lead Option package.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications			
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive		
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications		
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers		
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps		
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy		
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial		
Interface	interface.ti.com	Medical	www.ti.com/medical		
Logic	logic.ti.com	Security	www.ti.com/security		
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense		
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video		
RFID	www.ti-rfid.com				
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com		
Wireless Connectivity	www.ti.com/wirelessconnectivity				

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated